

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S54	19311	injection\$1enhanced\$gate\$1transist or or (injection adj enhanced adj gate adj transistor) or iegt or insulated\$1gate\$1bipolar\$1transisto r or (insulated adj gate adj bipolar adj transistor) or igt	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 13:07
S55	11	S54 and (negative\$1gate\$1capacitance or (negative near2 gate near2 capacitance))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 14:05
S56	16	S54 and (negative\$1gate\$1capacitance or (negative near4 gate near4 capacitance))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:57
S57	3491	(257/327-334).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/20 14:20
S58	3	S57 and (negative\$1gate\$1capacitance or (negative near4 gate near4 capacitance))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:42
S59	413493	(("257") or ("438")).CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/20 14:22
S60	53	S59 and (negative\$1gate\$1capacitance or (negative near4 gate near4 capacitance))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:04
S61	40	S54 and (dummy near (region or cell))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:25

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S62	57	S57 and (dummy near (region or cell))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:32
S63	14	S57 and ((oscillat\$3 or vibrat\$3) near3 gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:34
S64	154	S54 and ((oscillat\$3 or vibrat\$3) near3 gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:34
S65	1	(negative\$1gate\$1capacitance or (negative near4 gate near4 capacitance)) same (dummy near (region or cell))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:43
S66	11	(negative\$1gate\$1capacitance or (negative near4 gate near4 capacitance)) and (dummy near (region or cell))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:47
S67	13	(negative\$1gate\$1capacitance or (negative near4 gate near4 capacitance)) and ((oscillat\$3 or vibrat\$3 or instable or instability or stable or stability) near3 gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:52
S68	111	(dummy near2 (cell or region)) and ((oscillat\$3 or vibrat\$3 or instable or instability or stable or stability) near3 gate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:56
S69	24838	collector same emitter same base same gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:56

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S70	21	S69 and (negative\$1gate\$1capacitance or (negative near4 gate near4 capacitance))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 15:57
S71	147	S69 and (negative\$1gate\$1capacit\$4 or (negative near4 gate near4 capacit\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 16:00
S72	175	(S54 or S59) and (negative\$1gate\$1capacit\$4 or (negative near4 gate near4 capacit\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/20 16:08
S73	32	(collector and base and emitter and dummy).clm.	US-PGPUB	OR	ON	2006/03/20 16:10
S74	84	(collector and base and emitter and (second adj emitter)).clm.	US-PGPUB	OR	ON	2006/03/20 16:10